NXP 74F125 buffer datasheet

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The 74F125 provides four non-inverting buffer/line drivers with 3-state outputs. The 3-state outputs (nY) are controlled by the output enable input (nOE). A HIGH at nOE causes the outputs to assume a high-impedance OFF-state.

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74F125Quad buffers; 3-State
Rev. 4 — 23 January 2013

Product data sheet

1. **General description**

The 74F125 provides four non-inverting buffer/line drivers with 3-state outputs. The 3-state outputs (nY) are controlled by the output enable input (nOE). A HIGH at nOE causes the outputs to assume a high-impedance OFF-state.

Features and benefits 2.

■ High impedance NPN base inputs for reduced loading (20 μA in HIGH and LOW states)

Ordering information 3.

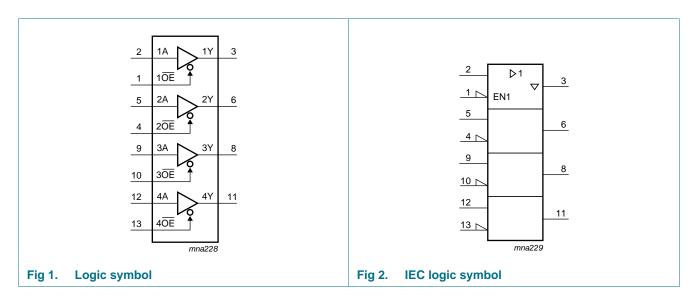
Table 1. **Ordering information**

Type number	Package							
	Temperature range	Name	Description	Version				
N74F125N	0 °C to +70 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1				
N74F125D	0 °C to +70 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1				



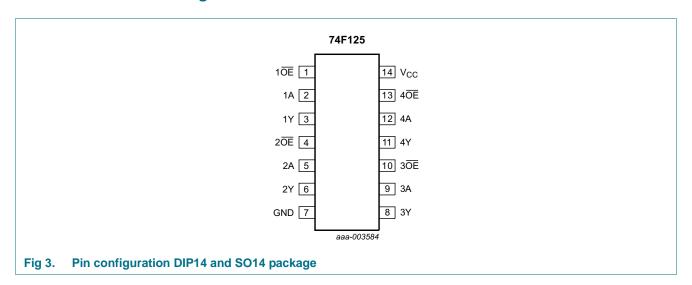
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4. Functional diagram



5. Pinning information

5.1 Pinning



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5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description	Unit load HIGH/LOW	Load value[1] HIGH/LOW
1OE to 4OE	1, 4, 10, 13	output enable input (active LOW)	1.0/0.033	20 μΑ/20 μΑ
1A to 4A	2, 5, 9, 12	data input	1.0/0.033	20 μΑ/20 μΑ
1Y to 4Y	3, 6, 8, 11	data output	750/106.7	15 mA/64 mA
GND	7	ground (0 V)	-	-
V _{CC}	14	supply voltage	-	-

^[1] One FAST Unit Load (UL) is defined as 20 μA in HIGH state, 0.6 μA in LOW state.

6. Functional description

Table 3. Function table[1]

Control	Input	Output
nOE	nA	nY
L	L	L
	Н	Н
Н	X	Z

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		<u>[1]</u> –0.5	+7.0	V
Vo	output voltage	output in HIGH-state	<u>[1]</u> -0.5	V_{CC}	V
I _{IK}	input clamping current	V _I < 0 V	-30	+5	mA
Io	output current	output in LOW-state	-	128	mA
T _{amb}	ambient temperature	in free air	<u>[2]</u> 0	70	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		4.5	5.0	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
I _{IK}	input clamping current		-18	-	-	mA
I _{OH}	HIGH-level output current		–15	-	-	mA
I _{OL}	LOW-level output current		-	-	64	mA
T _{amb}	ambient temperature		0		70	°C

9. Static characteristics

Table 6. Static characteristics

Symbol	Parameter	Conditions			25 °C		0 °C to +70 °C		Unit
				/lin	Typ[1]	Max	Min	Max	
V_{IK}	input clamping voltage	$V_{CC} = 4.5 \text{ V}; I_{IK} = -18 \text{ mA}$	_	1.2	-0.73	-	-1.2	-	V
V_{OH}	HIGH-level output	$V_{CC} = 4.5 \text{ V}; V_{IL} = 0.8 \text{ V}; V_{IH} = 2.0 \text{ V}$							
	voltage	$I_{OH} = -3 \text{ mA}$							
		V _{CC} = ±10 %		-	-	-	2.4	-	V
		V _{CC} = ±5 %		-	3.3	-	2.7	-	V
		$I_{OH} = -15 \text{ mA}$							
		V _{CC} = ±10 %		-	-	-	2.0	-	V
V_{OL}	LOW-level output	$V_{CC} = 4.5 \text{ V}; V_{IL} = 0.8 \text{ V}; V_{IH} = 2.0 \text{ V}$							
VO	voltage	I _{OL} = 64 mA							
		V _{CC} = ±10 %		-	-	-	-	0.55	V
		V _{CC} = ±5 %		-	0.42	-	-	0.55	V
II	input leakage current	$V_{CC} = 0 \text{ V}; V_I = 7.0 \text{ V}$		-	-	-	-	100	μΑ
I _{IH}	HIGH-level input current	$V_{CC} = 5.5 \text{ V}; V_I = 2.7 \text{ V}$		-	-	-	-	20	μΑ
I _{IL}	LOW-level input current	$V_{CC} = 5.5 \text{ V}; V_I = 0.5 \text{ V}$		-	-	-	-20	-	μΑ
l _{OZ}	OFF-state output current	V _{CC} = 5.5 V							
		V _O = 2.7 V		-	-	-	-	50	μΑ
		V _O = 0.5 V		-	-	-	-50	-	μΑ
Io	output current	V _{CC} = 5.5 V	[2]	-	-	-	-225	-100	mA
I _{CC}	supply current	V_{CC} = 5.5 V; V_I = GND or V_{CC}							
		outputs HIGH-state		-	17	-	-	24	mA
		outputs LOW-state		-	28	-	-	40	mA
		outputs OFF-state		-	25	-	-	35	mΑ

^[1] All typical values are measured at $V_{CC} = 5 \text{ V}$.

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^[2] No more than one output should be tested at a time, and the duration of the test should not exceed one second.

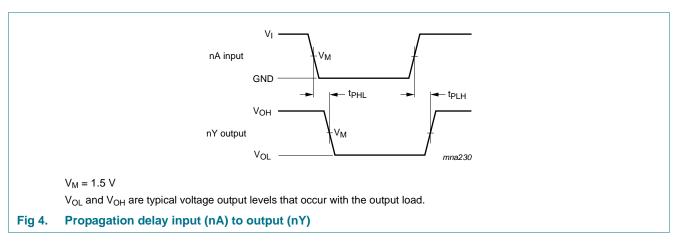
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10. Dynamic characteristics

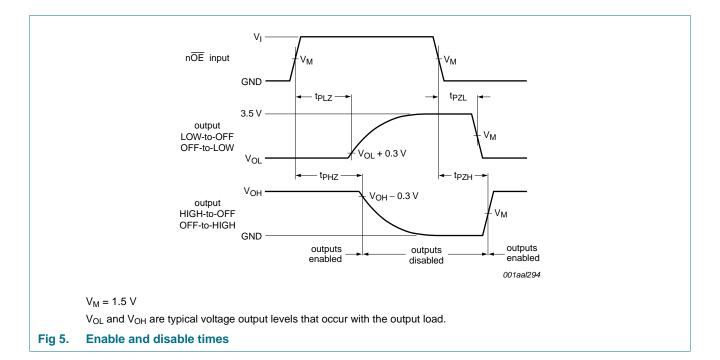
Table 7. Dynamic characteristics GND = 0 V. Test circuit is shown in Figure 6.

Symbol	Parameter	Conditions	25 °C;	25 °C; V _{CC} = 5.0 V			0 °C to +70 °C; $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	
			Min	Тур	Max	Min	Max	
t _{PLH}	LOW to HIGH propagation delay	nA to nY, see Figure 4	2.0	4.0	6.0	2.0	6.5	ns
t _{PHL}	HIGH to LOW propagation delay	nA to nY; see Figure 4	3.0	5.5	7.5	3.0	8.0	ns
t _{PZH}	OFF-state to HIGH propagation delay	nOE to nY; see Figure 5	3.5	5.5	7.5	3.5	8.5	ns
t _{PZL}	OFF-state to LOW propagation delay	nOE to nY; see Figure 5	4.0	6.0	8.0	4.0	9.0	ns
t _{PHZ}	HIGH to OFF-state propagation delay	nOE to nY; see Figure 5	1.5	3.5	5.0	1.5	6.0	ns
t _{PLZ}	LOW to OFF-state propagation delay	nOE to nY; see Figure 5	1.5	3.5	5.5	1.5	6.0	ns

11. Waveforms



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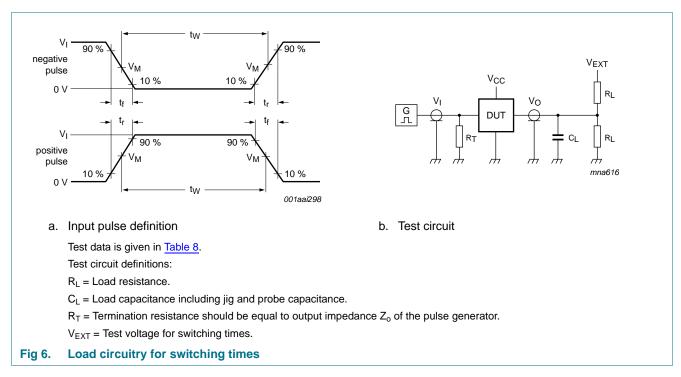


Table 8. Test data

Input				Load	Load		V _{EXT}		
VI	fi	t _W	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t_{PZL}, t_{PLZ}	
3.0 V	1 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	open	open	7.0 V	

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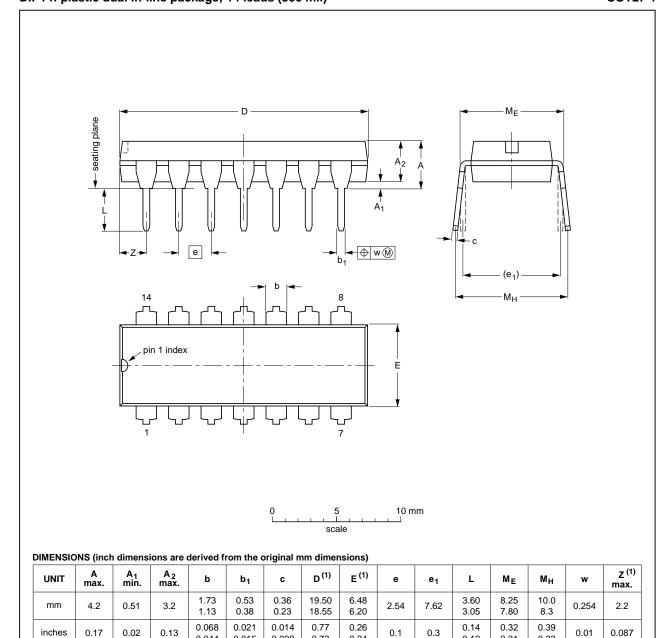
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12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.044

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT27-1	050G04	MO-001	SC-501-14		99-12-27 03-02-13

0.009

0.015

Fig 7. Package outline SOT27-1 (DIP14)

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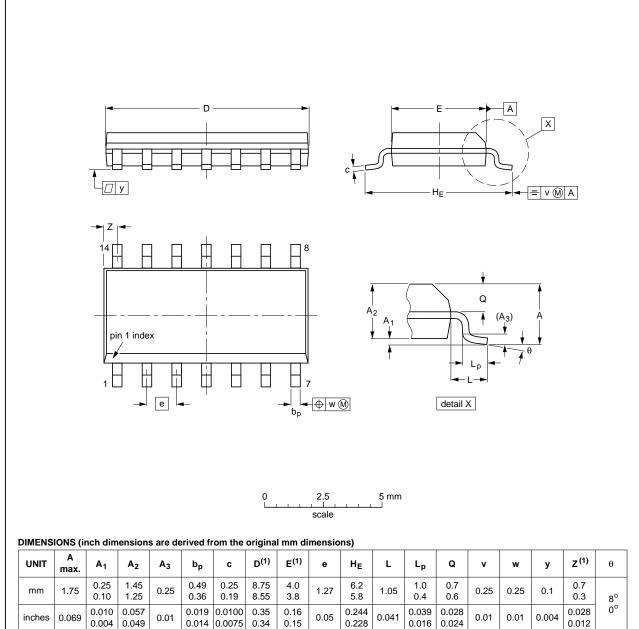
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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



inches 0.069

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION ISSUE DAT	
SOT108-1	076E06	MS-012			99-12-27 03-02-19

Fig 8. Package outline SOT108-1 (SO14)

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13. Abbreviations

Table 9. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
LSTTL	Low-power Schottky Transistor-Transistor Logic
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
CDM	Charge-Device Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74F125 v.4	20130123	Product data sheet	-	74F125 v.3
Modifications:	 Features and 	d benefits: Changed mA into μ	A (errata).	
74F125 v.3	20130118	Product data sheet	-	74F125 v.2
Modifications:		of this data sheet has been redeated NXP Semiconductors.	esigned to comply w	ith the new identity
	 Legal texts h 	ave been adapted to the new	company name whe	re appropriate.
74F125 v.2	19890328	Product data sheet	-	74F125 v.1

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15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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